NSN 5961-01-630-2362

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-630-2362 **Inclosure Material:** Glass and metal **Overall Length:** 60.2 millimeters **Terminal Length:** 25.4 millimeters **Overall Diameter:** 6.35 millimeters **Function For Which Designed:** Rectifier **Electrode Internally-electrically Connected To Case:** Source **Mounting Method: Terminal Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 280.0 reverse voltage, total rms **Current Rating Per Characteristic:** 5.0 amperes average forward current averaged over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Product Name:** Rectifier, super fast, 5.0 ampere **Special Features:** Low forward voltage drop, high current capability, high reliability and high surge current capability; recurrent peak reverse voltage is 400v **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**